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<tr>
<td>Citation</td>
<td>Renewable Energy Research and Applications (ICRERA), 2012 International Conference on, Article number 6477321; 2012</td>
</tr>
<tr>
<td>Issue Date</td>
<td>2012</td>
</tr>
<tr>
<td>URL</td>
<td><a href="http://hdl.handle.net/10069/32398">http://hdl.handle.net/10069/32398</a></td>
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Sn-modified Ni-nanowire array films prepared by electrodeposition and their electrochemical properties as an anode material of lithium-ion batteries

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Abstract— Ni-nanowire array films were prepared by general galvanostatic electrodeposition employing a polycarbonate membrane filter (pore diameter: 0.1 μm or 0.8 μm) as a template and subsequent dissolution of the membrane filter in chloroform. Thereafter the Ni-nanowire array films were modified with Sn by pulsed electrodeposition. Morphology of Sn-modified Ni-nanowire array films obtained was largely dependent on the microstructure of the membrane filter and the conditions of pulsed electrodeposition of Sn. It was confirmed that uniform deposition of Sn right into the Ni-nanowire array structure improved charge-discharge characteristics of the Sn-modified Ni-nanowire array films as an anode of lithium-ion batteries.

Keywords; tin; nickel; nanowire; anode; lithium-ion battery; electrodeposition

I. INTRODUCTION

Lithium-ion batteries are generally utilized as a rechargeable electric source in different portable application fields such as mobile phones and laptop computers, because the electrode materials (graphite as an anode and lithium cobaltite as a cathode) show highly-efficient lithium-insertion/deinsertion properties. However, the capacity of the conventional lithium-ion batteries is insufficient as an electric source for large-scale application such as electric vehicles. Recently, metallic Sn metal as well as Sn-based materials (e.g., SnO2, SnO and Sn-based alloy) are very noteworthy as a potential anode material of lithium-ion batteries, because their theoretical capacities are large (994 mAh g-1 for the metallic Sn) in comparison with that of graphite (372 mAh g-1). However, their large expansion and shrinkage of volume associated with charge and discharge process (i.e., alloying and de-alloying of Sn with lithium) markedly reduce the charge-discharge cyclic performance of the Sn-based anode. Therefore, numerous efforts have been directed to improving the charge-discharge cyclic performance by controlling their compositions and microstructure [1-12].

We have already reported some potential Sn-based anode materials. Mesoporous (m-) SnO2 powder with high specific surface area (over 200 m2 g-1) and small crystallite size (ca. 2 nm) was employed as a starting material and then the use of the Sn-based anode material fabricated by reducing the m-SnO2 powder in argon and subsequently in hydrogen at elevated temperatures largely enhanced the charge-discharge cyclic performance [13]. Introduction of a macroporous cobalt or nickel film between an electrodeposited Sn film and a copper substrate (current collector) by electrodeposition utilizing polymethylmethacrylate as a template was also quite effective in improving the charge-discharge cyclic performance [14]. Based on these previous results, Sn has been electrochemically modified on Ni-nanowire array films fabricated by electrodeposition employing a polycarbonate membrane filter as a template, and charge-discharge characteristics of the obtained Sn-modified Ni-nanowire array films as an anode of lithium-ion batteries have been investigated in this study.

II. EXPERIMENTAL

A. Preparation of nickel-nanowire array films

After Au was deposited on one side of a polycarbonate membrane filter (MF-n, n (pore diameter shown in the catalog): 0.1 μm or 0.8 μm, Advantec Toyo Ltd.) by ion sputtering, it was attached on a Cu foil (diameter: 2 cm, thickness: 20 μm) by double-faced adhesive conductive tape. Ni was electrodeposited in the electrolytic aqueous solution containing NiSO4・6H2O (120 g dm-3) and H3BO4 (45 g dm-3) at a voltage of -1.0 V at 40°C for an appropriate electrolytic period [15]. After the MF-n filter was dissolved in chloroform, a Ni-nanowire array (Ni-n) film was obtained. A conventional Ni film on Cu foil (Ni-c) was also fabricated by electrodeposition in the same solution, as a reference.

B. Electrodeposition of Sn on nickel-nanowire array films

Ni-n films were immersed in the electrolytic aqueous solution containing SnSO4・6H2O (50 g dm-3), o-cresolsulfonic acid (50 g dm-3), β-naphthol (1 g dm-3), gelatin (1 g dm-3) and H2BO4 (90 g dm-3), and Sn was deposited on the Ni-n films by pulsed electrodeposition (condition P(a): 6.5 mA cm-2 for 30 s and 32.5 mA cm-2 for 0.1 s, 10 times, condition P(b): 6.5 mA cm-2 for 30 s and 32.5 mA cm-2 for 0.1 s, 10 times, condition P(b): 6.5 mA cm-2 for 30 s and 32.5 mA cm-2 for 0.1 s, 10 times,
cm² for 30 s and 65.0 mA cm⁻² for 0.1 s, 10 times). The Sn-modified Ni-nanowire array films obtained were denoted as Sn-M/Ni-n (M (electrodeposition condition): P(a) or P(b)). Sn was deposited by galvanostatic electrodeposition (condition G: 6.5 mA cm⁻² for 300 s) also on the reference Ni-c film. The reference composite film was denoted as Sn-G/Ni-c. All samples obtained were heat-treated at 240°C for 12 h under vacuum condition controlled by a general rotary pump. Morphology of all samples was observed by scanning electron microscopy (SEM, JEOL, JCM-5700).

C. Fabrication of test cell and its charge-discharge characteristics

An exploded schematic drawing of a hand-made test cell is shown in Fig. 1. First, a mixed solution of ethylene carbonate (EC) and dimethyl carbonate (DMC) (EC : DMC = 1 : 2 in mass ratio) containing 1 M LiPF₆ as an electrolyte was immersed in both a glass filter (Advantec Toyo Ltd.; GA-100) and a separator (Celgard, LLC; 2400). Then they were sandwiched between the Sn-M/Ni-n or the Sn-G/Ni-c film on the Cu foil as a working electrode and a Li foil with a stainless mesh as a counter electrode. Thereafter they were set in a hand-made test cell in an argon-filled glove box. Charge-discharge characteristics of the test cells obtained were galvanostatically measured in the cell voltage range of 0.02~1.50 V (vs. Li/Li⁺) at a current density of 0.02 mA cm⁻² by a typical battery test system (Toyo System Co., Ltd., TOSCAT-3100H).

III. RESULTS AND DISCUSSION

A. Morphology of polycarbonate membrane filters, nickel-nanowire array films and tin-modified nickel-nanowire array films

Figures 2 and 3 show SEM photographs of MF-n filters and Ni-n films. The number density of nanowires of Ni-0.1 film prepared, ca. 4.5 x 10⁷ cm⁻², was almost similar to that of pores on the surface of the MF-0.1 filter, ca. 5.7 x 10⁸ cm⁻², and the size of nanowires of the Ni-0.1 film was ca. 0.11 μm in diameter and ca. 3.3 μm in length. As for the Ni-0.8 film, the number density of nanowires, ca. 3.1 x 10⁸ cm⁻², was also almost equal to that of pores on the surface of the MF-0.8 filter, ca. 2.5 x 10⁸ cm⁻², and the size of nanowires of the Ni-0.8 film was ca. 0.95 μm in diameter and ca. 3.2 μm in length. The aspect ratio of the nanowires of the Ni-0.1 film (ca. 30) was much larger than that of the Ni-0.8 film (ca. 3.4). In addition, the nanowires of the Ni-0.1 film were relatively dense, whereas the morphology of edge parts of the nanowires of the Ni-0.8 film was nanotube-like structure. This is probably because a small amount of gold was deposited also on the inside wall of relatively-large pores of the MF-0.8 filter when it was deposited on one side of the MF-0.8 filter by ion sputtering (pre-treatment process before the Ni electrodeposition) and

![Figure 1](image1.png)

Figure 1. An exploded schematic drawing of a hand-made test cell.

![Figure 2](image2.png)

Figure 2. SEM photographs of an MF-0.1 filter and a Ni-0.1 film.

![Figure 3](image3.png)

Figure 3. SEM photographs of an MF-0.8 filter and a Ni-0.8 film.
thus Ni was easily electrodeposited along the gold-coated inner wall. These results show that Ni was effectively electrodeposited into the almost all pores of the MF-n filters.

Figure 4 shows SEM photographs of Sn-M/Ni-0.1 films. The amount of Sn deposited in the Sn-P(b)/Ni-0.1 film was apparently larger than that in the Sn-P(a)/Ni-0.1 film, because the amount of electric charge transferred under the period of electrodeposition for the Sn-P(b)/Ni-0.1 film was larger than that for the Sn-P(a)/Ni-0.1 film. In addition, Sn in the Sn-P(b)/Ni-0.1 film was uniformly deposited right into the nanowire array structure of the Ni-0.1 film, while a little amount of Sn in the Sn-P(a)/Ni-0.1 film was partially deposited among the nanowires of the Ni-0.1 film and its majority was found near the top of the Ni-0.1 film. The behavior implies a large effect of the current density during the pulsed electrodeposition on the morphology of Sn deposited, but the

Figure 5. SEM photographs of Sn-M/Ni-0.8 films.

Figure 6. Representative chronopotentiograms of test cells fabricated with Sn-M/Ni-n films and a Sn-G/Ni-c film in the cell voltage range of 0.02–1.50 V (vs. Li/Li+ ) at a current density of 0.02 mA cm⁻².
exact reason for this phenomenon is not clear at present. For the Sn-M/Ni-0.8 film, on the other hand, Sn was only deposited on the top of nanowires of the Ni-0.8 film and it was hardly found inside the nanowire array structure. Generally, metal was easily electrodeposited at the edge and the protruding surface of electrodes. As the number of Ni nanowires of the Sn-M/Ni-0.8 film was much smaller than that of the Sn-M/Ni-0.1 film, electric fields easily concentrated on the top of Ni nanowires of the Sn-M/Ni-0.8 film in comparison with that of the Sn-M/Ni-0.1 film and thus the Sn bulk might be deposited only at the surface of the Ni-0.8 film.

B. Charge-discharge characteristics of test cells

Figure 6 shows representative chronopotentiograms of all test cells fabricated with Sn-M/Ni-n films and a Sn-G/Ni-c film in the cell voltage range of 0.02~1.50 V (vs. Li/Li+) at a current density of 0.02 mA cm\(^{-2}\). Figure 7 shows charge and discharge cyclic performances of all test cells fabricated with Sn-M/Ni-n films and a Sn-G/Ni-c film, which were obtained from the results of their chronopotentiograms (Fig. 6). Hereafter, test cells fabricated with the Sn-M/Ni-n film and the Sn-G/Ni-c film are referred to as Sn-M/Ni-n and Sn-G/Ni-c cells, respectively. Alloying and de-alloying of Sn with Li proceeded in charge and discharge processes, respectively. The steep potential change at the capacity of ca. 420 and 440 mAh g\(^{-1}\) of the Sn-P(a)/Ni-0.8 and the Sn-P(b)/Ni-0.8 cells in Figs. 6 (c) and (d), respectively, was anticipated to arise from temporal current interruption. Most potential-capacity curves of all test cells in Fig. 6 exhibited three potential plateaus in the range of 1.1~1.2 V, ca. 0.8~0.9 V and 0.6~0.7 V in the discharge (alloying process of Sn with Li), which may be ascribed to the reaction expressed by equations (1)~(3), respectively [1, 16, 17].

\[
\begin{align*}
5\text{Sn} + 2\text{Li} \rightarrow & \quad \text{Li}_2\text{Sn}_5 \quad (1) \\
\text{Li}_2\text{Sn}_5 + 3\text{Li} \rightarrow & \quad 5\text{LiSn} \quad (2) \\
3\text{LiSn} + 4\text{Li} \rightarrow & \quad \text{Li}_7\text{Sn}_3 \quad (3)
\end{align*}
\]

In addition, a continuous decrease in the potential less than 0.6 V means further alloying of Li\(_7\)Sn\(_3\) with Li (i.e., from Li\(_7\)Sn\(_3\) to Li\(_5\)Sn\(_2\), Li\(_3\)Sn\(_2\), Li\(_2\)Sn\(_2\) and lastly Li\(_2\)Sn\(_3\)) [1, 16, 17]. The Sn-G/Ni-c cell showed relatively large charge and discharge capacities of over 700 mAh g\(^{-1}\) until 10th cycle (charge) and 6th cycle (discharge). The capacities reduced drastically after 11th cycle (discharge) and 7th cycle (charge), probably owing to the large volume change in Sn. The capacity of the Sn-M/Ni-0.8 cell was much smaller than that of the Sn-G/Ni-c cell even in the early cycles (ca. 500 mAh g\(^{-1}\) for the Sn-P(a)/Ni-0.8 cell and less than 300 mAh g\(^{-1}\) for the Sn-P(b)/Ni-0.8 cell as a discharge capacity), probably because the brittle contact between Sn and the Ni-0.8 film (see Fig. 5) might collapse after the first lithium alloying and de-alloying processes. On the other hand, the Sn-M/Ni-0.1 cell maintained relatively large charge and discharge capacities (>600 mAh g\(^{-1}\)) in the early cycles (ca. 500 mAh g\(^{-1}\) for the Sn-P(a)/Ni-0.8 cell and less than 300 mAh g\(^{-1}\) for the Sn-P(b)/Ni-0.8 cell as a discharge capacity), probably because the brittle contact between Sn and the Ni-0.8 film might collapse after the first lithium alloying and de-alloying processes. On the other hand, the Sn-M/Ni-0.1 cell maintained relatively large charge and discharge capacities (>600 mAh g\(^{-1}\)) in the early cycles (ca. 500 mAh g\(^{-1}\) for the Sn-P(a)/Ni-0.8 cell and less than 300 mAh g\(^{-1}\) for the Sn-P(b)/Ni-0.8 cell as a discharge capacity), probably because the brittle contact between Sn and the Ni-0.8 film (see Fig. 5) might collapse after the first lithium alloying and de-alloying processes. On the other hand, the Sn-M/Ni-0.1 cell maintained relatively large charge and discharge capacities (>600 mAh g\(^{-1}\)) in the early cycles (ca. 500 mAh g\(^{-1}\) for the Sn-P(a)/Ni-0.8 cell and less than 300 mAh g\(^{-1}\) for the Sn-P(b)/Ni-0.8 cell as a discharge capacity), probably because the brittle contact between Sn and the Ni-0.8 film (see Fig. 5) might collapse after the first lithium alloying and de-alloying processes.

IV. CONCLUSION

After Ni was galvanostatically electrodeposited on the well-developed pores of MF-n filters and subsequently the filters were dissolved in chloroform, a Ni-n film was obtained in this study. The morphology of nanowires of the Ni-n films almost reflected that of pores of the MF-n filters. The morphology of Sn deposited in the Ni-n films by pulsed electrodeposition was dependent on the microstructure of the membrane filter (i.e., the number density and diameter of Ni nanowires prepared) and the conditions of the pulsed electrodeposition. Among all Sn-M/Ni-n cells tested, the Sn-P(b)/Ni-0.1 cell showed the most excellent charge-discharge characteristics as an anode material of lithium-ion batteries.
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